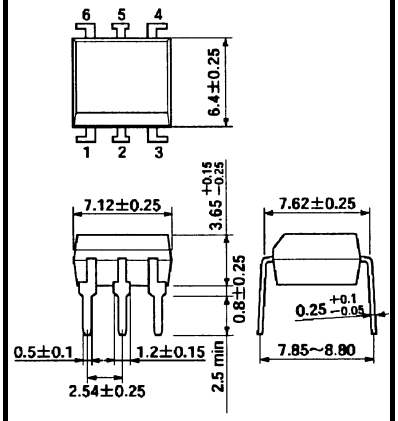
TOSHIBA Photocoupler Photorelay

TLP592A

Telecommunications
Measurement and Control Equipment
Data Acquisition System
Measurement Equipment

Unit: mm



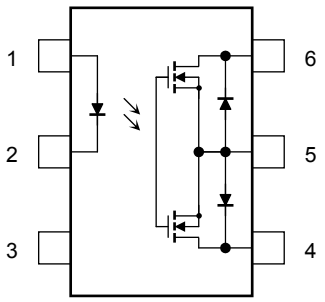
JEDEC	—
JEITA	—
TOSHIBA	11-7A8

Weight: 0.4 g (typ.)

The Toshiba TLP592A consists of a gallium arsenide infrared emitting diode optically coupled to a photo-MOSFET in a 6-pin DIP package. This photorelay has higher output current rating than phototransistor-type photocoupler; hence, it is suitable for use as On/Off control for high current.

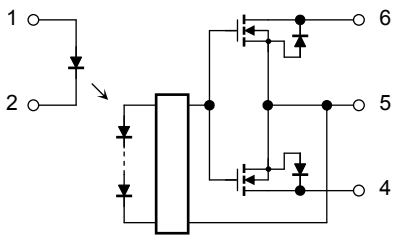
- Normally open (1-form-A) device
- Peak off-state voltage: 60 V (min)
- Trigger LED current: 3 mA (max)
- On-state current: 500 mA (max)
- On-state resistance: 2 Ω (max)
- Isolation voltage: 2500 Vrms (min)
- UL recognized: UL1557, File No.E67349

Pin Configuration (top view)



1: Anode
2: Cathode
4: Drain D1
5: Source
6: Drain D2

Schematic



Absolute Maximum Ratings (Ta = 25°C)

Characteristics			Symbol	Rating	Unit
LED	Forward current		I_F	50	mA
	Forward current derating (Ta ≧ 25°C)		ΔI_F/°C	−0.5	mA/°C
	Peak forward current (100 μs pulse, 100 pps)		I_{FP}	1	A
	Reverse voltage		V_R	5	V
	Junction temperature		T_j	125	°C
Detector	Off-state output terminal voltage		V_{OFF}	60	V
	On-state current	A connection	I_{ON}	500	mA
		B connection		500	
		C connection		1000	
	Forward current derating (Ta ≧ 25°C)	A connection	ΔI_{ON}/°C	−5.0	mA/°C
		B connection		−5.0	
		C connection		−10.0	
	Junction temperature		T_j	125	°C
Storage temperature			T_{stg}	−55 to 125	°C
Operating temperature			T_{opr}	−40 to 85	°C
Lead soldering temperature (10 s)			T_{sol}	260	°C
Isolation voltage (AC, 1 min, R.H. ≦ 60%) (Note 1)			BV_S	2500	Vrms

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.
Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook (“Handling Precautions”/“Derating Concept and Methods”) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

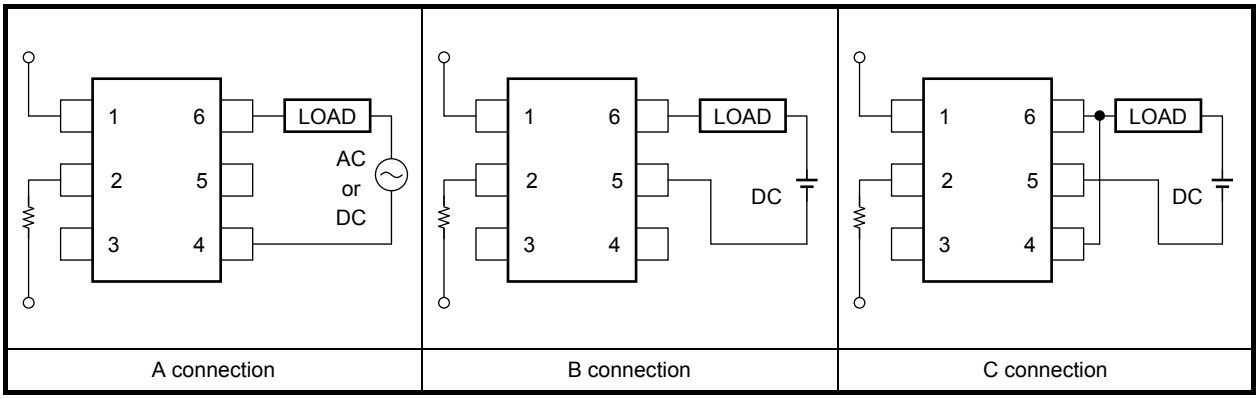
Note 1: LED pins are shorted together. Detector pins are also shorted together.

Recommended Operating Conditions

Characteristics	Symbol	Min	Typ.	Max	Unit
Supply voltage	V_{DD}	—	—	48	V
Forward current	I_F	5	7.5	25	mA
On-state current	I_{ON}	—	—	500	mA
Operating temperature	T_{opr}	−20	—	65	°C

Note: Recommended operating conditions are given as a design guideline to obtain expected performance of the device. Additionally, each item is an independent guideline respectively. In developing designs using this product, please confirm specified characteristics shown in this document.

Circuit Connections



A connection | B connection | C connection

Electrical Characteristics Ta = 25°C)

Characteristics		Symbol	Test Condition	Min	Typ.	Max	Unit
LED	Forward voltage	V_F	I_F = 10 mA	1.0	1.15	1.3	V
	Reverse voltage	I_R	V_R = 5 V	—	—	10	μA
	Capacitance	C_T	V = 0, f = 1 MHz	—	30	—	pF
Detector	Off-state current	I_{OFF}	V_{OFF} = 60 V	—	—	1	μA
	Capacitance	C_{OFF}	V = 0, f = 1 MHz	—	130	—	pF

Coupled Electrical Characteristics (Ta = 25°C)

Characteristics		Symbol	Test Condition	Min	Typ.	Max	Unit
Trigger LED current		I_{FT}	I_{ON} = 500 mA	—	1.6	3	mA
Return LED current		I_{FC}	I_{OFF} = 100 μA	0.1	—	—	mA
On-state resistance	A connection	R_{ON}	I_{ON} = 500 mA, I_F = 5 mA	—	1	2	Ω
	B connection		I_{ON} = 500 mA, I_F = 5 mA	—	0.5	1	
	C connection		I_{ON} = 1000 mA, I_F = 5 mA	—	0.25	—	

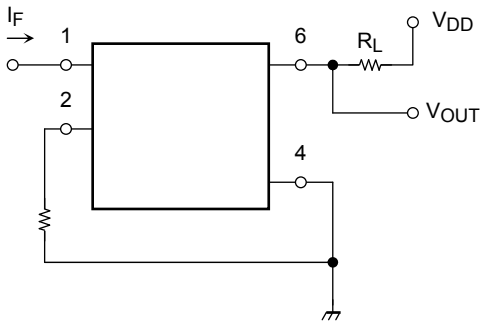
Isolation Characteristics (Ta = 25°C)

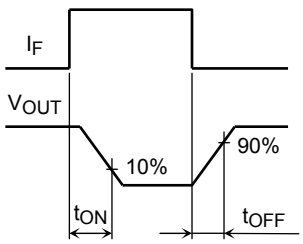
Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Capacitance input to output	C_S	V_S = 0 V, f = 1 MHz	—	0.8	—	pF
Isolation resistance	R_S	V_S = 500 V, R.H. ≦ 60%	5×10^{10}	10^{14}	—	Ω
Isolation voltage	BV_S	AC, 1 min	2500	—	—	Vrms
		AC, 1 s, in oil	—	5000	—	
		DC, 1 min, in oil	—	5000	—	Vdc

Switching Characteristics (Ta = 25°C)

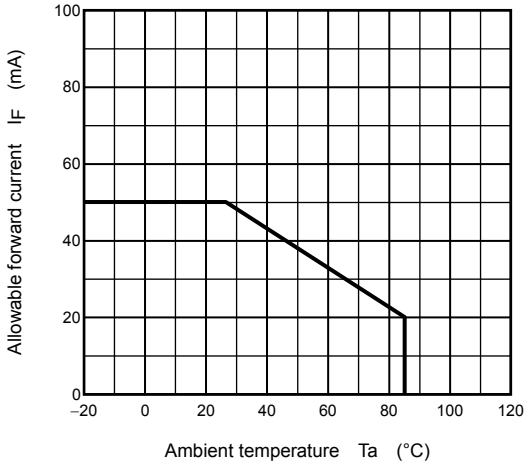
Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Turn-on time	t_{ON}	R_L = 200 Ω (Note 2)	—	0.8	2	ms
Turn-off time	t_{OFF}	V_{DD} = 20 V, I_F = 5 mA	—	0.1	0.5	

Note 2: Switching time test circuit

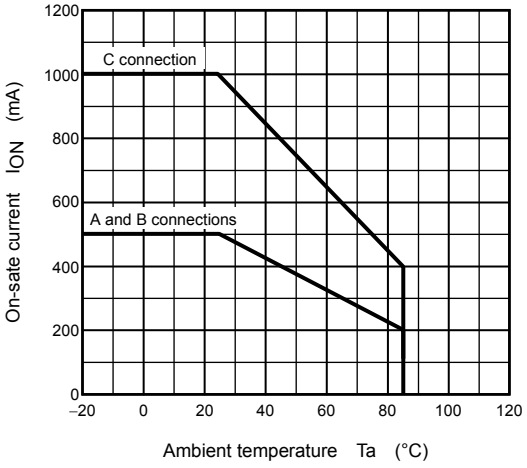




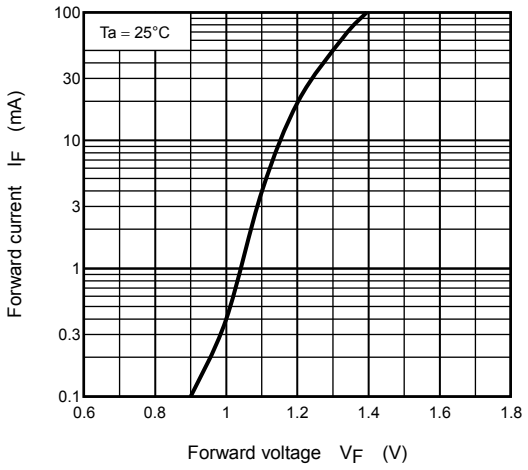
I_F – Ta



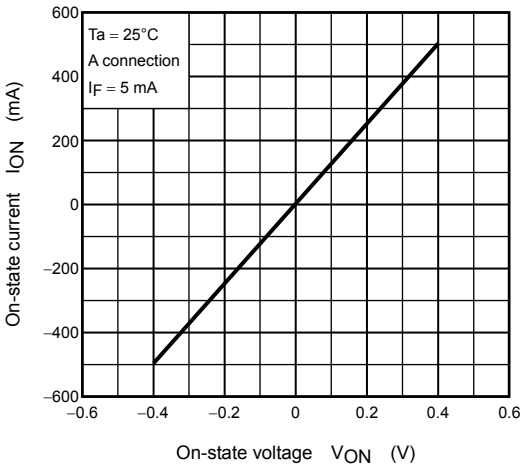
I_{ON} – Ta



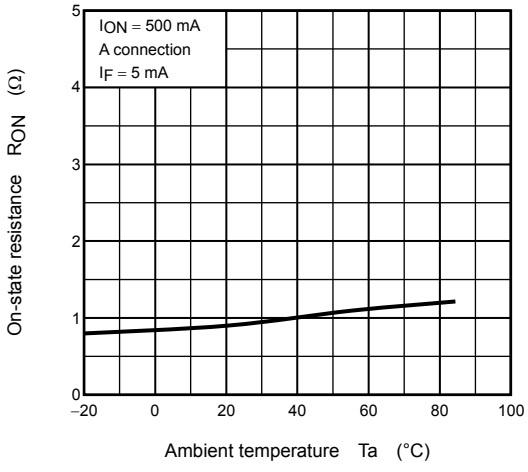
I_F – V_F



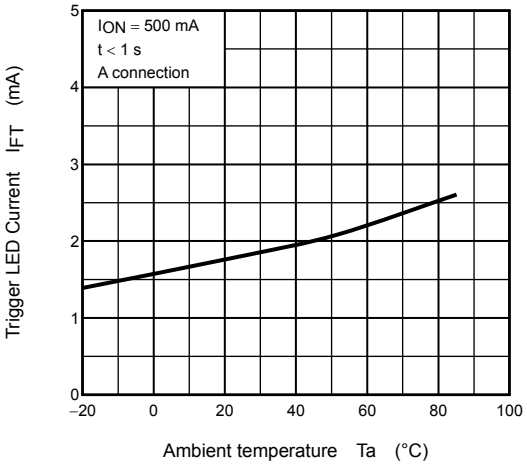
I_{ON} – V_{ON}



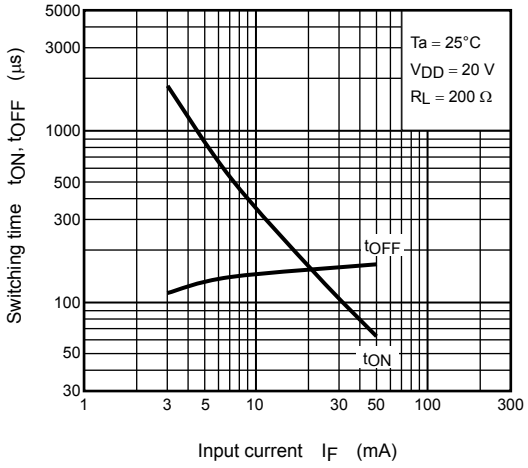
R_{ON} – Ta



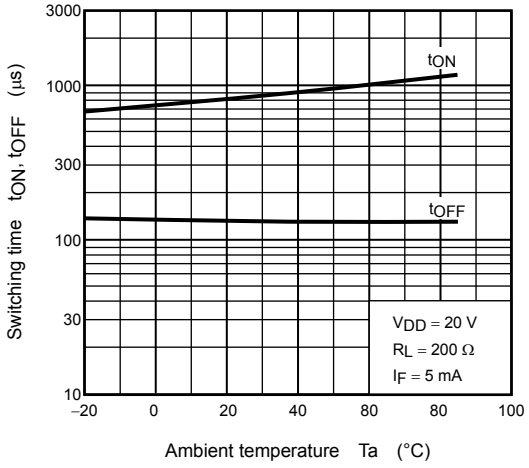
I_{FT} – Ta



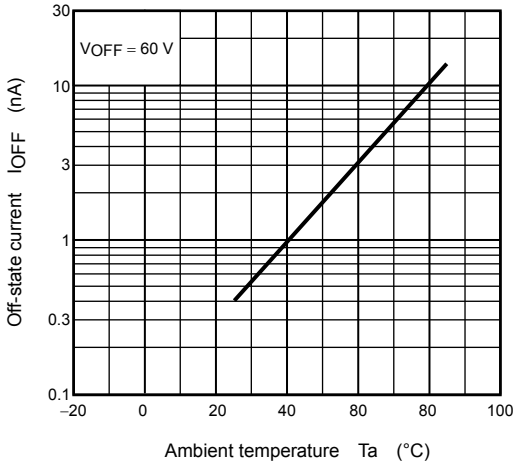
t_{ON}, t_{OFF} – I_F



t_{ON}, t_{OFF} – Ta



I_{OFF} – Ta



RESTRICTIONS ON PRODUCT USE

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